

# Review - Analog

## Ch. 1

### 1. Resistive Circuits

a) Kirchoff's Laws: i) Loop Thm:  $\sum V_i = 0$

(ii) Branch Thm:  $I_{into} = I_{out}$   
junction

b) Ohm's Law:  $V = IR$

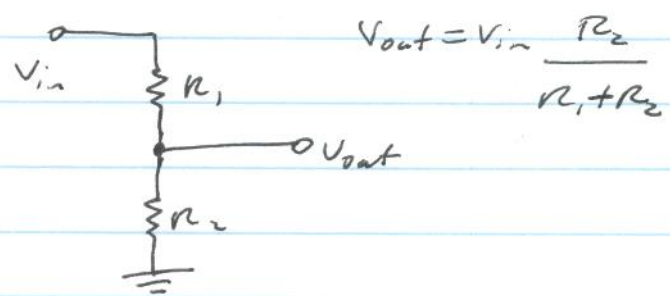
c)  $R_{out}, Z_{out}, R_{in}, Z_{in}$

d) Thevenin model: To find  $V_{Th}, R_{Th}$

i)  $V_{Th} = V(\text{open circuit}) = V_{oc}$

ii)  $R_{Th} = \frac{V(\text{open circuit})}{I(\text{short circuit})} = \frac{V_{oc}}{I_{sc}}$   
put wire across output

e) Voltage Dividers



f) Power:  $P = IV$

g) Problem w/ Source Loading - need  $R_L \gg R_s$   
to prevent loading.

# RC Circuits

$$Q = CV \quad V = IZ$$

$$Z_c = \frac{1}{j\omega C}$$

## a) General

- i) time domain vs. frequency domain
- ii) step response vs. sine response
- iii) I leads V by  $90^\circ$  ELI the ICEman.

## b) Important RC Circuits

i) integrator (low-pass)

$$V_{out} = \frac{1}{RC} \int V_{in}(t) dt$$

differentiator (high-pass)

$$V_{out} = RC \frac{dV_{in}}{dt}$$

ii) filters

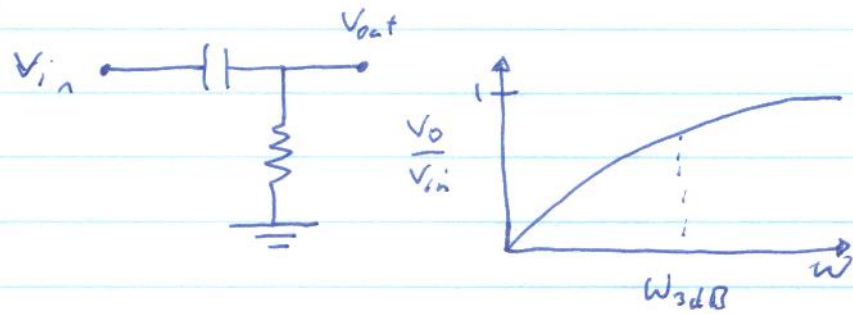
1.  $f_{3dB}$  ( $\omega_{3dB}$ )

$$dB: 10 \log \frac{P_2}{P_1}, 20 \log \frac{V_2}{V_1}$$

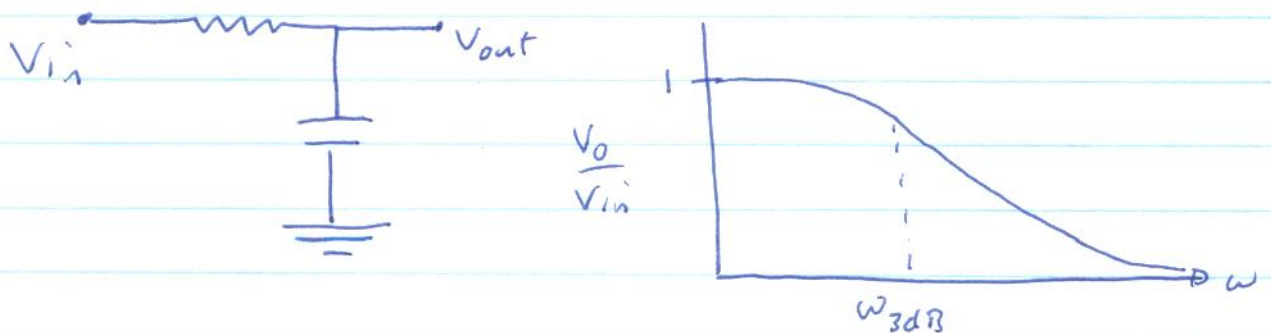
2. phase-shift

$$3dB \Rightarrow V_{out} = \frac{V_{in}}{\sqrt{2}}$$

1) High-pass filter:



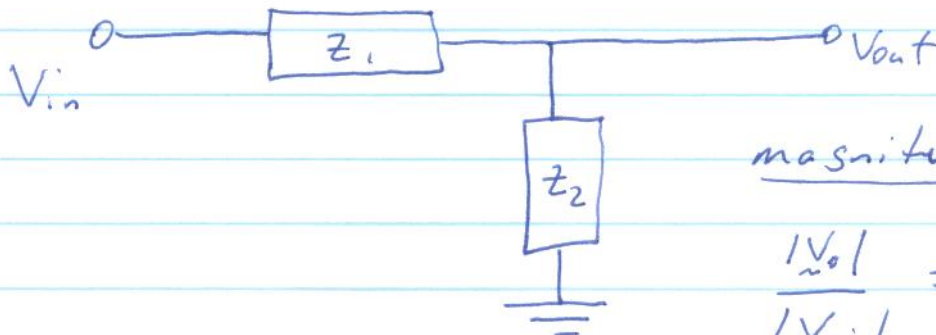
2) Low-pass filter:



(3)

- 2. phase-shift - need complex analysis
- ac circuits

### Generalized Voltage Divider



magnitudes:

$$\frac{|V_{out}|}{|V_{in}|} = \frac{|Z_2|}{|Z_1 + Z_2|}$$

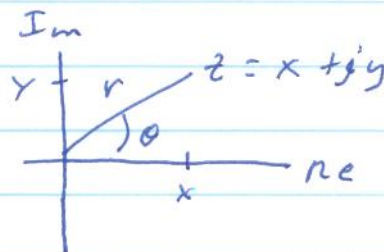
### Magnitude + Phase

$$\underline{V}_{in} = V_{in} e^{j\omega t}$$

$$\underline{V}_{in} = \underline{I} \underline{Z}_{TOT} \Rightarrow \underline{I} = \frac{\underline{V}_{in}}{\underline{Z}_{TOT}}$$

$$\underline{V}_{out} = \underline{I} \underline{Z}_2 = \frac{V_{in} e^{j\omega t}}{|\underline{Z}_{TOT}|^2} \underline{Z}_{TOT}^* \underline{Z}_2$$

Complex Numbers:

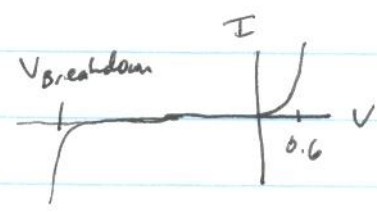


$$r = \sqrt{x^2 + y^2} \quad \tan \theta = \frac{y}{x} \quad z = x + jy = r e^{j\theta}$$

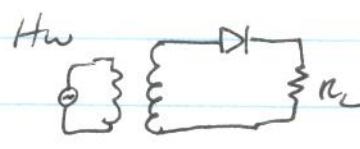
$$e^{j\theta} = \cos \theta + j \sin \theta$$

Transformer:  $\frac{V_p}{N_p} = \frac{V_s}{N_s}$

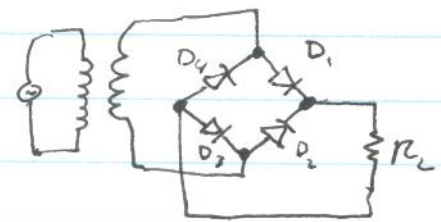
### 3. Diode Circuits



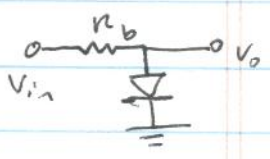
a) Rectifiers



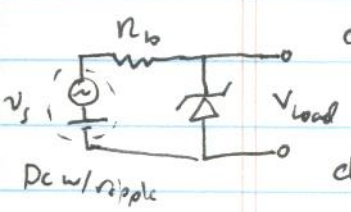
FW Bridge



b) Clamp



c) Zener voltage reference



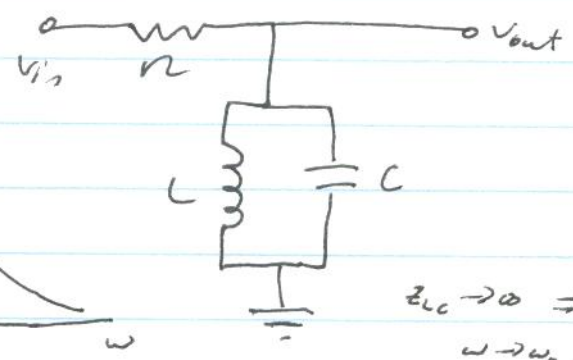
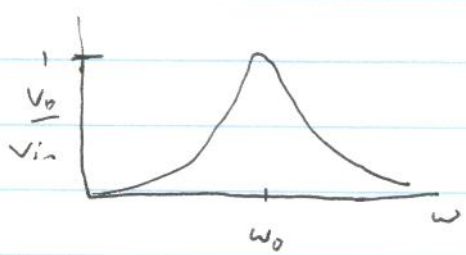
d) power-supply

- ripple - add low pass filter  
choose C  $\Rightarrow RC \gg \frac{1}{f}$

### 4. LC Circuits

LC resonant circuit

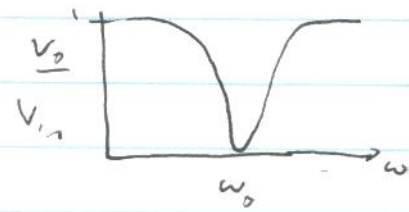
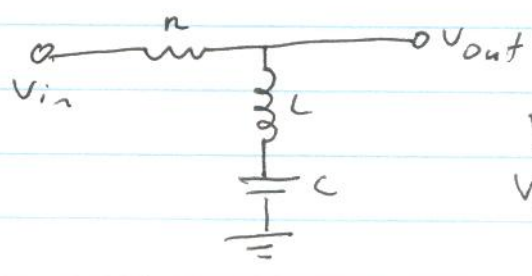
$\omega_0 = \frac{1}{\sqrt{LC}}$



$Z_{LC} \rightarrow \infty \Rightarrow \omega \rightarrow \omega_0$

Notch filter

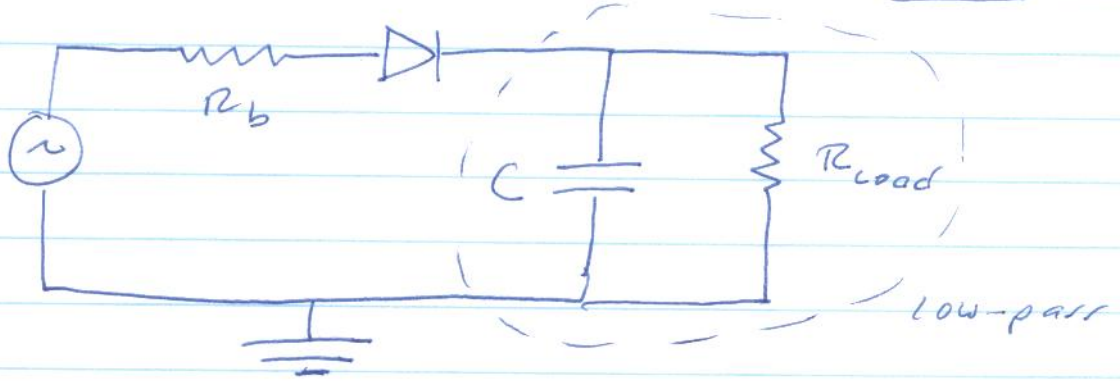
$\omega_0 = \frac{1}{\sqrt{LC}}$



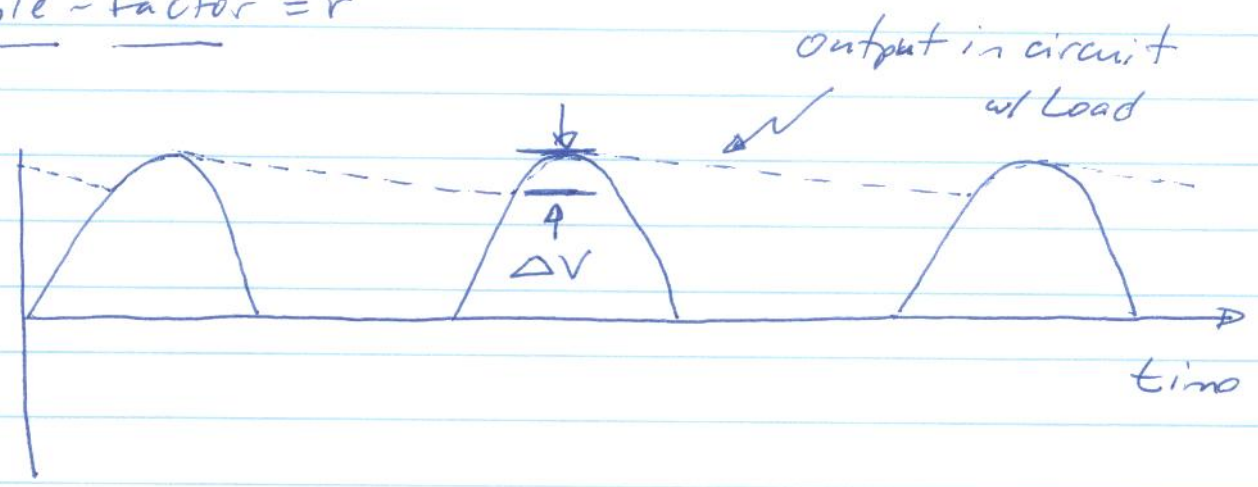
### 5. Bandpass Filter

- homework; chain HP + LP together w/ correct selection of  $\omega_{3dB}$  for each to match bandpass range

Power Supply - Diode Rectifier + Low-Pass Filter



ripple factor  $\equiv r$



$$r = \frac{\Delta V}{V_{ac}} = \frac{1}{f R_{load} C}$$

so pick capacitor large enough to give desired ripple factor for a given load (+ frequency).

Essential Concept: Charged capacitor is discharging between cycles through  $R_{load}$ .

# Chapter 2

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## Transistors

### 1. General

a) Ground Rules

i)  $V_{CE} > 0$

ii) BE + BC act like diodes

iii)  $I_C, I_D, V_{CE}$  have maxima



b) Two models

i) current amplifier  $I_C = h_{FE} I_B = \beta I_D$

$\beta \sim 100$

ii) voltage amp (Ebers-Moll)

$$I_C \approx I_S e^{V_{BE}/V_T}$$

$$V_T = 25.3 \text{ mV} = \frac{kT}{e}$$

(Troem)

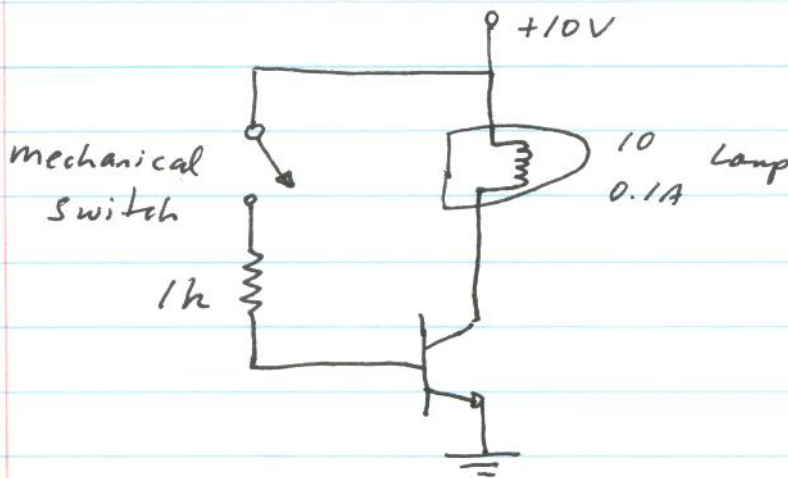
c) Biasing - design rule - set voltage at base,

not current.

## 2. Important Circuits

### a) Switch

Here, with transistor saturated, usual  $\beta$  rule does not apply:  $I_c =$  typically about  $10 I_B$ .

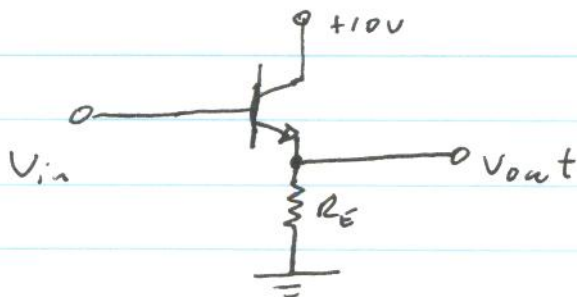


$$V_B \approx V_E + 0.6V$$

### b) Emitter Follower

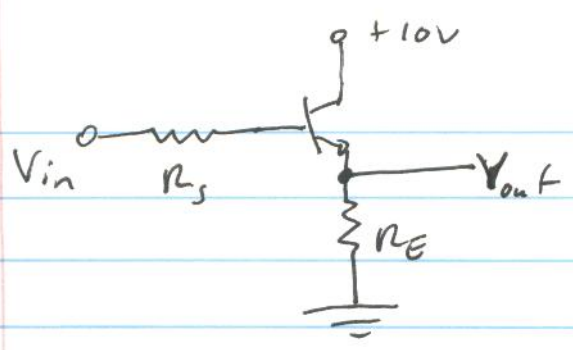
- impedance changing: here is one of the few cases where you need to use  $\beta$  in your calculation (but a worst-case  $\beta$ ).

- a variation is the push pull which can swing both ways.



$$V_E \approx V_B - 0.6V$$

$$r_{in} \approx h_{FE} R_E \text{ (looking into base)}$$



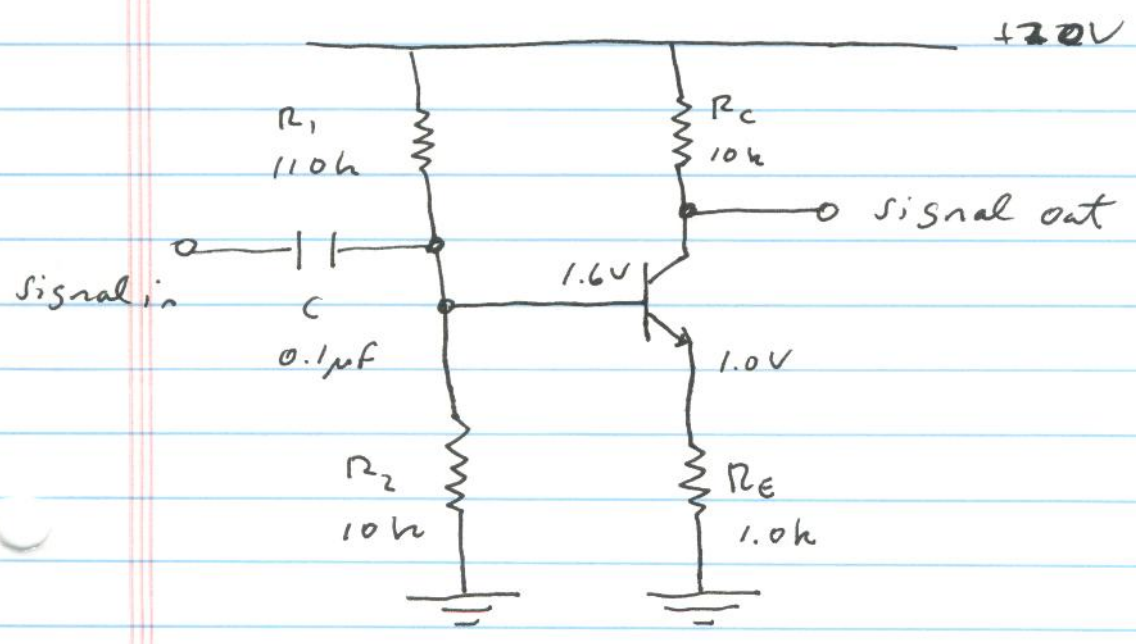
$$R_{out} = \frac{R_S}{h_{FE} + 1}$$

Looking into emitter  
 (we ignore RE in parallel w/ Rout)

### c. Common-emitter amplifier

- degenerated emitter resistor (placing of resistor b/w emitter and ground (or other negative supply) in common emitter amp. Source of term: gain is reduced or "degenerated" (performance is much improved however!)

- distortion ← greed for gain



### 3. General Problems

- swings an ac input in both directions on output  
solution: biasing the base - use a voltage divider

- temperature effects

drift of  $I_c$  (+ ∴ of  $V_{out}$ ) with  $T$  since

$$V_{BE} = -2.1mV/^\circ C \quad (\text{Ebers moll } I_c \approx I_s e^{V_{BE}/V_T})$$

this will cause gain to significantly

strongly depend on  $T$ !!

vary w/ signal & will distort the signal

i) solution: use  $R_E$  as feedback - degenerated emitter common-emitter amplifier

This reduces voltage gain:  $G = -\frac{R_c}{R_E}$

solution - bypass emitter (put  $C$  in parallel w/  $R_E$ )  
+ add small  $R$  in  $C$  leg

$$r_e = \frac{25}{I_c(mA)} \Omega \quad (\text{intrinsic emitter resistance})$$

ii) solution to temp problem - compensation - see differential amp.

- Miller effect - problem with capacitance

solution - differential amp.

# Worked Example - Bypass Common-Emitter Amp

(High-Gain, Temp. Stable amplifier).

7. Choose  $C_1$ . Note that at signal freq.

$$R_{in} \approx R_{Th}(\text{bias}) \parallel h_{FE}(r_e + R_E)$$

$$\approx 20k \parallel 100 \times 200$$

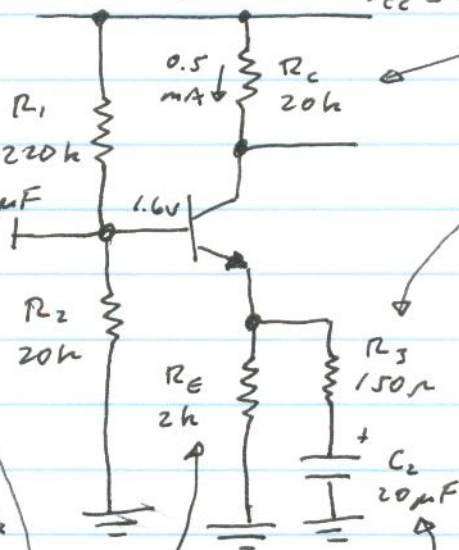
$$= 10k$$

$$\Rightarrow C_1 = \frac{1}{2\pi \cdot 50 \cdot 10k}$$

$$\approx 0.33 \mu F$$

1. Choose  $I_Q$

$V_{CC} = +20V$



2. To center  $V_{out}$  for  $I_Q = 0.5mA$ ,  $R_C = 20k$

5. Choose  $R_E$  for req'd gain.

$$G = \frac{R_C}{r_e + (R_E \parallel R_3)}$$

and  $r_e = 50\Omega @ I_C = 0.5mA$ .

$$Thus \ 100 = \frac{20k}{50\Omega + R_3} \text{ and } R_3 = 150\Omega$$

(note effect of  $R_E$  negligible)

4. Find  $R_1:R_2$  ratio to put  $V_B \approx 1.6V$ :

$$\frac{1.6V}{18.4V} = \frac{R_2}{R_1} \Rightarrow R_1 = 11.5R_2$$

--- then ---

Set  $R_{Th}(\text{bias}) \ll R_{in}(\text{base})$ :

$$R_{in}(\text{base}) \approx h_{FE} R_E = 200k$$

So  $R_{Th}(\text{bias}) \ll 20k$ .

Let  $R_2 = 20k$ , since

$$R_1 \gg R_2 \Rightarrow R_{Th}(\text{bias}) \approx R_2$$

3. Put  $V_E \approx 1V$ , for temp. stab.  
 $\Rightarrow R_E = 2k$

6. Choose  $C_2$ .

Circuit  $f_{3dB} = 100Hz \Rightarrow$  this filter's

$f_{3dB} \approx 50Hz$ . relevant "R" is  $R_3 + r_e$

$$\Rightarrow C_2 = \frac{1}{2\pi f_{3dB} (R_3 + r_e)} = 16 \mu F$$

use  $20 \mu F$  (or  $22 \mu F$ )